

## FEATURES

- Voltage Measuring Range: 0 to  $\pm 1000\text{V}$
- Output Voltage Range: 0 to  $\pm 5\text{V}$
- Both AC and DC Voltage Measurement
- Galvanic Isolated Voltage Rating: 3000 Vrms
- Very Low Leakage Current: 60uA @ 3KVrms 60Hz
- Large Signal Bandwidth: 22 KHz
- Fast Response Time: < 25  $\mu\text{s}$
- Overall Accuracy: Better than  $\pm 1\%$  of Full-Scale
- Low Nonlinearity:  $\pm 0.006\%$  Max
- High Common Mode Voltage Rejection: 107 dB
- High Input Resistance:  $1.5\text{ M}\Omega$
- Operating Temperature Range: - 40 °C to 85 °C
- Low Output Voltage Offset Drift:  $\pm 0.33\text{ mV}/^\circ\text{C}$
- Very Low Voltage Gain Drift:  $\pm 0.035\% /^\circ\text{C}$
- Operating Power Supply Range:  $\pm 11\text{V}$  to  $\pm 13\text{V}$
- Low Quiescent Current: < 48mA/0.8mA
- Built-in Isolated Power Supply
- Small Footprint: 1.5" x 1" x 0.5" (38.1x25.4x12.7mm)
- Weight: 0.741 oz (21 g)
- RoHS Compliant
- MTBF  $1318 \times 10^3$  Hrs (25°C)  $653 \times 10^3$  Hrs (85°C)
- Excellent Water and Thermal Shock Resistance
- Flame Retardant (UL 94 V-O)

## DESCRIPTION

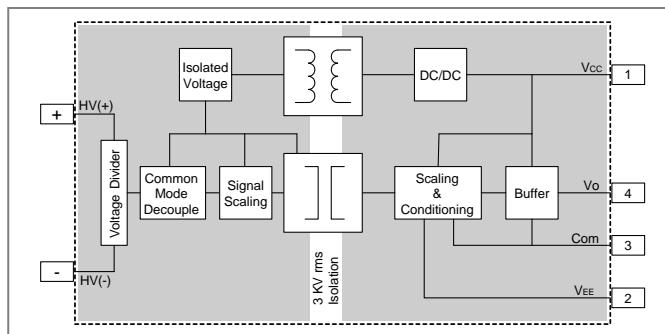
The V1000-ISO is a precision high bandwidth voltage transducer that is capable of measuring AC and DC voltages up to  $\pm 1000\text{V}$  with  $\pm 1\%$  accuracy. The device is rated 3KV rms galvanic isolation with advanced voltage sensing, common mode decoupling, and isolation technology built-in to ensure safe and accurate high voltage measurement. Excellent dynamic characteristics provide large signal bandwidth of 22 KHz and high common mode rejection of 107 dB @ 60Hz. The V1000-ISO is ideal for high voltage sensing that requires high accuracy, fast response, high common mode rejection, wide operating temperatures (- 40 °C to 85 °C ), and a small footprint.

The V1000-ISO is easy to use and does not require additional components. The device has an internal integrated isolation power supply and circuitry for direct high voltage sensing. Just apply nominal  $\pm 12\text{Vdc}$  power and high voltage to be sensed, the device will output a galvanic isolated voltage signal with voltage attenuation gain of 200. High voltage input pins are "+" and "-" with maximum differential voltage of  $\pm 1000\text{V}$  and voltage rated 3KV rms with respect to ground. Operating power supply requirement is  $\pm 12\text{Vdc}$  nominal (range:  $\pm 11\text{V}$  to  $\pm 13\text{V}$ ). Pin 1 is +12V input, Pin 2 is -12V input, and pin 3 is  $\pm 12\text{V}$  return. Pin 4 is the output with full scale output voltage of  $\pm 5\text{V}$ . Pins "+", "-" and Pins 1, 2, 3, 4 are isolated with reinforced insulation of 3KVrms isolation rating.

Typical output to input voltage gain is 1:200. The V1000-ISO has excellent gain linearity with typical  $\pm 0.001\%$  nonlinearity ( $\pm 100\text{V}$  to  $\pm 1000\text{V}$ ) and maximum  $\pm 0.006\%$  nonlinearity at low voltage range (<  $\pm 100\text{V}$ ). Gain deviation as a function of temperature is typically  $\pm 0.02\% /^\circ\text{C}$ . Typical output voltage offset drift is  $0.33\text{ mV} /^\circ\text{C}$ .

High voltage input resistance is typical  $1.5\text{ M}\Omega$  and it requires very small power from high voltage bus circuit being sensed. For example, power drawn from a 1000Vdc high voltage bus is 0.67 watts. The input resistance is optimized with dynamic characteristics, DC characteristics, and thermal performance of the device.

The V1000-ISO requires small quiescent current (48 mA max) from its +12Vdc input power supply and 0.8 mA max from -12V. The internal integrated isolation power supply is derived from the +12Vdc input to power up high voltage side circuitry.

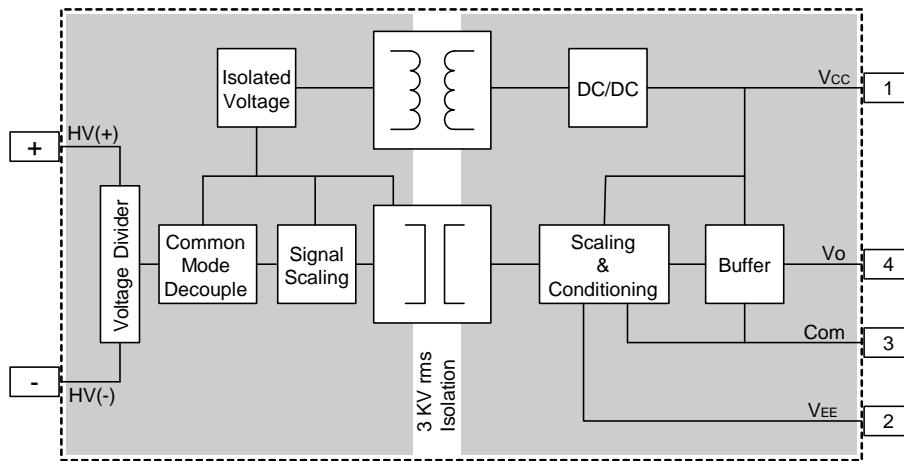


Functional Block Diagram

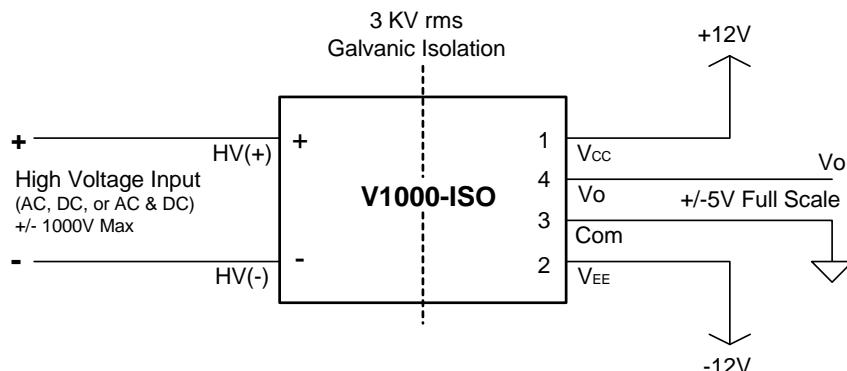


V1000-ISO Picture (1.5" x 1" x 0.5" Excluding Pins)

## FUNCTIONAL BLOCK DIAGRAM



## TYPICAL APPLICATION WIRING DIAGRAM



## ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Minimum	Maximum	Units
Storage Temperature	T <sub>S</sub>	-45	+ 95	°C
Ambient Operating Temperature	T <sub>A</sub>	-40	+ 85	°C
Supply Voltages	V <sub>CC</sub> [Pin 1]	+ 10.8	+ 13.2	V
	V <sub>EE</sub> [Pin 2]	- 13.2	- 10.8	V
	Com [Pin 3]	0	0	V
Steady State Input Voltage	[Pin +] - [Pin -]	-1050	+ 1050	V
Transient Input Voltage (2 Seconds)	[Pin +] - [Pin -]	-1200	+ 1200	V
Output Voltage	V <sub>O</sub> [Pin 4]	- 6	+ 6	V
Pins Soldering	Temperature		260	°C
	Time Duration		15	S

## RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Minimum	Maximum	Units
Ambient Operating Temperature	T <sub>A</sub>	- 40	+ 85	°C
Supply Voltages	V <sub>CC</sub> [Pin 1]	+ 11	+ 13	V
	V <sub>EE</sub> [Pin 2]	- 13	- 11	V
Input Voltage Range	[Pin +] - [Pin -]	-1000	+ 1000	V

## ELECTRICAL CHARACTERISTICS

At TA = +25°C , V<sub>cc</sub> = +12V V<sub>ee</sub> = -12V, and R<sub>L</sub> = 10kΩ, unless otherwise noted.

PARAMETER	CONDITIONS	Fig	Note	V100-ISO			UNITS
				MIN	TYP	MAX	
<b>ISOLATION</b>							
Isolation Voltage Rating	Input to Output, 60Hz AC, 60sec 100% Tested	21	1	3000			V rms
Leakage Current	Input to Output, 3000 Vrms @ 60Hz			49	60		μA rms
<b>GAIN</b>							
Nominal Gain	Output to Input Voltage Ratio	1-2	2		1/200		V/V
Overall Accuracy		3	3		± 0.6	± 1	%
Gain Vs Temperature	-40 °C to 85 °C	6	4		± 0.02	± 0.035	% / °C
Nonlinearity		4	5		± 0.001	± 0.006	%
<b>COMMON MODE REJECTION</b>							
Frequency Response	60Hz 500KHz	20,23	6	107 80			dB dB
Transient Immunity	1000V Step Excitation(>10KV/μs)	19,24	7			0.6	V
<b>INPUT VOLTAGE</b>							
Voltage Range	Continuous Operation	22	8	± 1000			V
Resistance	Between Pin "+" and Pin "-"				1.5		MΩ
<b>OUTPUT VOLTAGE</b>							
Voltage Range					± 5		V
Offset Voltage					± 20	± 32	mV
Voltage Offset Drift	Deviation from offset at 25 °C	22	9			± 0.33	mV / °C
Current Drive						± 5	mA
Capacitive Load	In parallel with 1KΩ				1000 pF		
Ripple Voltage	Vin=0V, Scope Bandwidth 100 MHz				± 25	± 40	mV
<b>Dynamic Response</b>							
Full Signal Bandwidth	Input Voltage Amplitude: 1000V	7-15	10	22			KHz
Propagation Delay	Pulse Transient Test	16-18 22	11		2.8	4.4	μS
Slew Rate					1.2	2.5	V / μS
<b>Power Supply</b>							
Supply Voltage				± 11	± 12	± 13	Vdc
Quiescent Current (V <sub>cc</sub> )	Over Rated Input Voltage Range			31	37	48	mA
Quiescent Current (V <sub>EE</sub> )					0.3	0.8	mA
<b>Temperature Range</b>							
Operating	Continuous Full Input Voltage			-40		85	°C
Storage	Non-Power			-45		95	°C

### PERFORMANCE CHARACTERISTICS

At  $T_A = +25^\circ\text{C}$ ,  $V_{cc} = +12\text{V}$   $V_{ee} = -12\text{V}$ , and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.

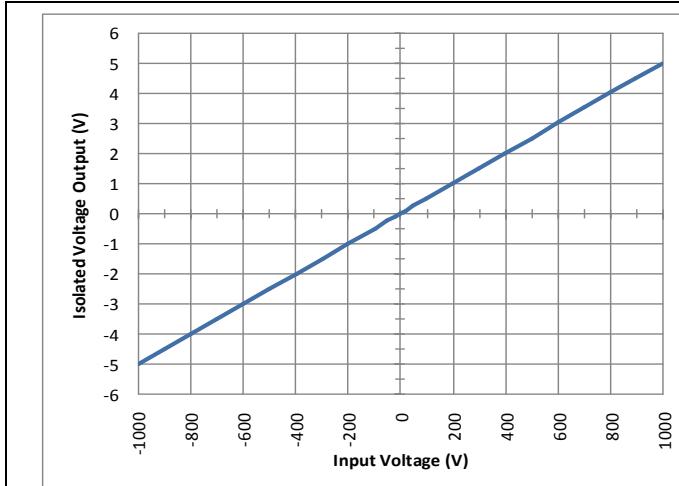


Figure 1: Input to Output Voltage

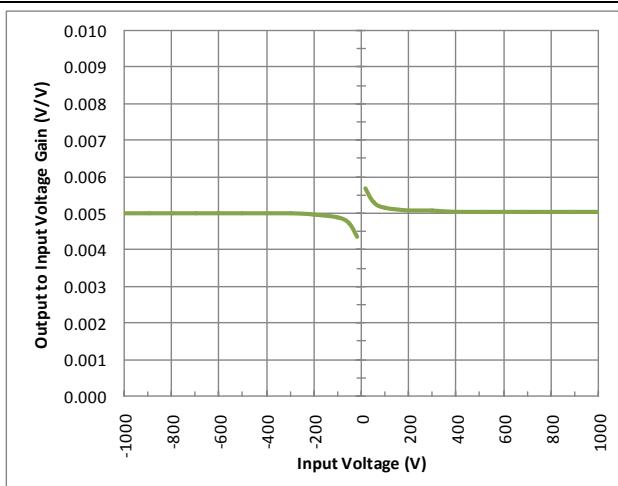


Figure 2: Output to Input voltage Gain

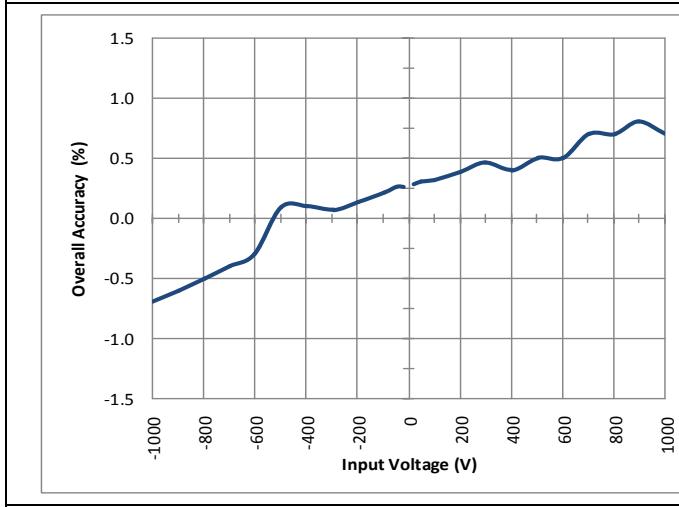


Figure 3: Voltage Sensing Overall Accuracy

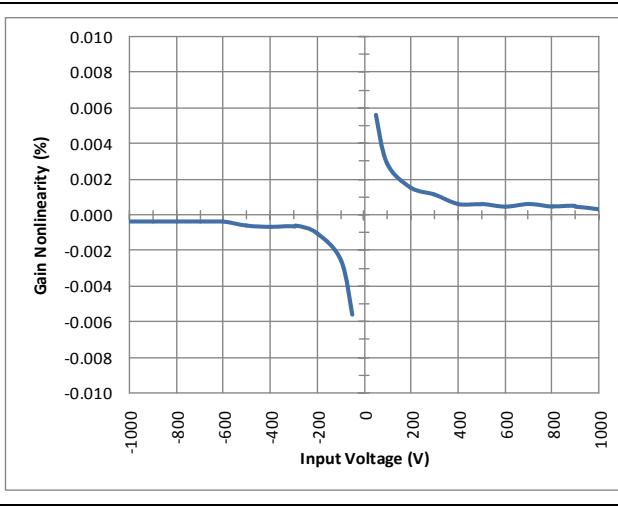


Figure 4: Gain Nonlinearity

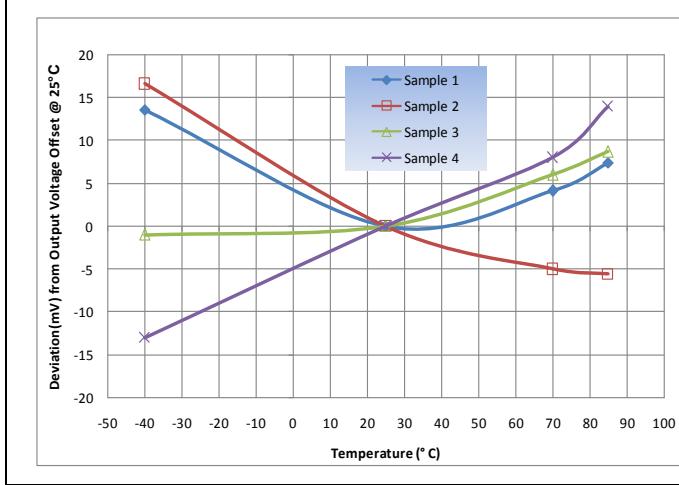


Figure 5: Output Voltage Drift Vs. Temperature

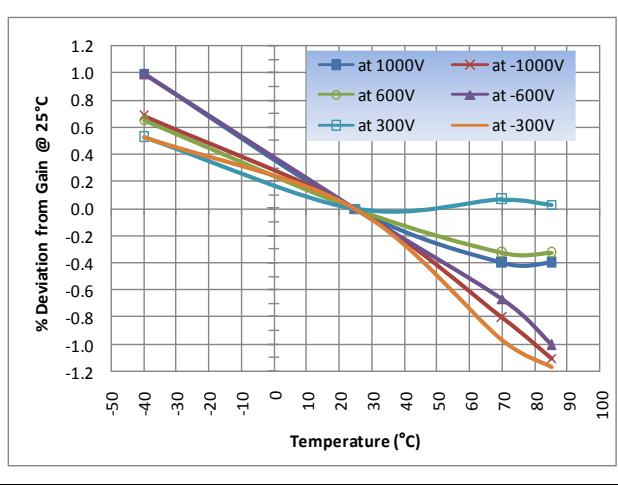
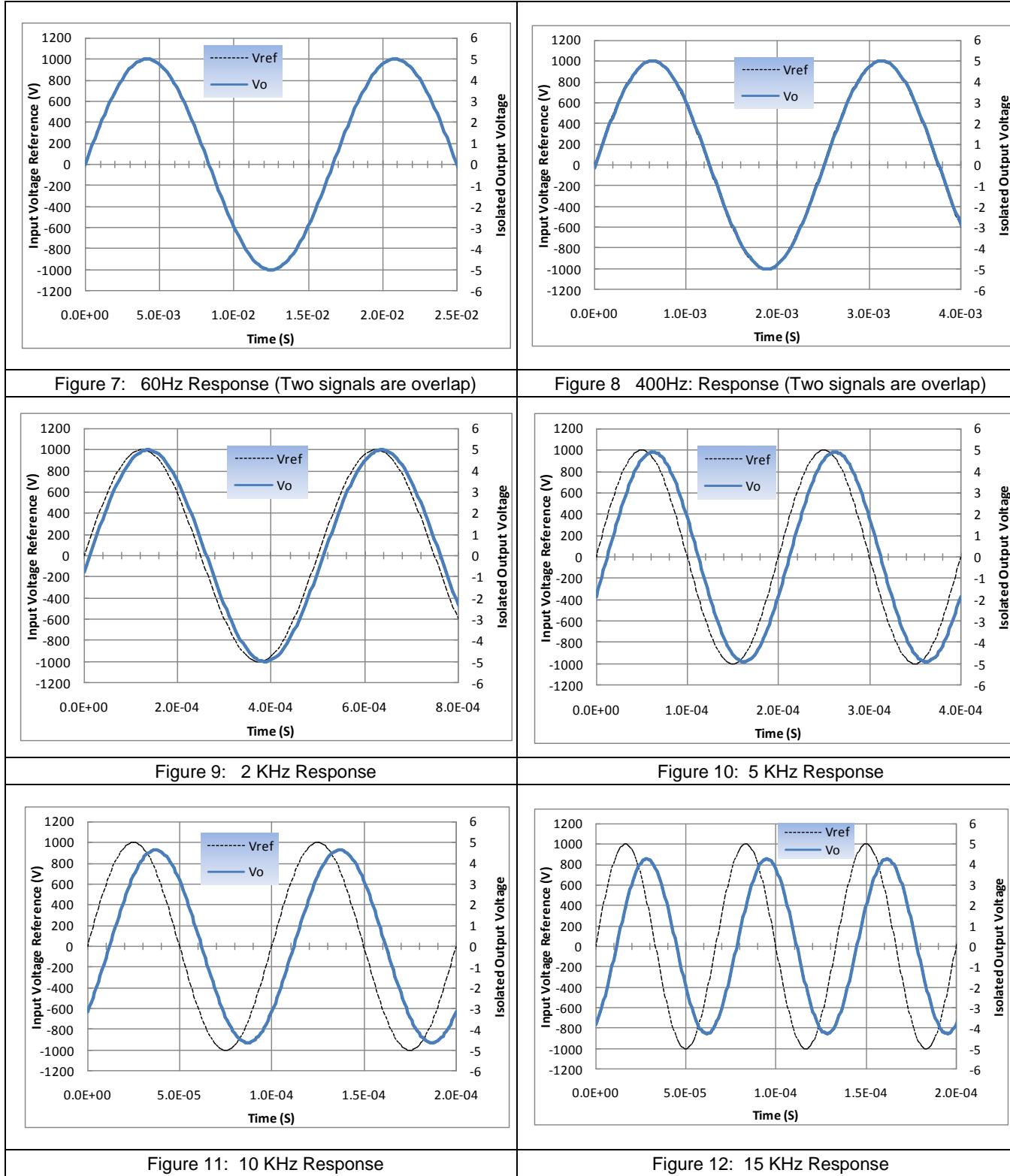


Figure 6: Gain Percentage Deviation Vs. Temperature

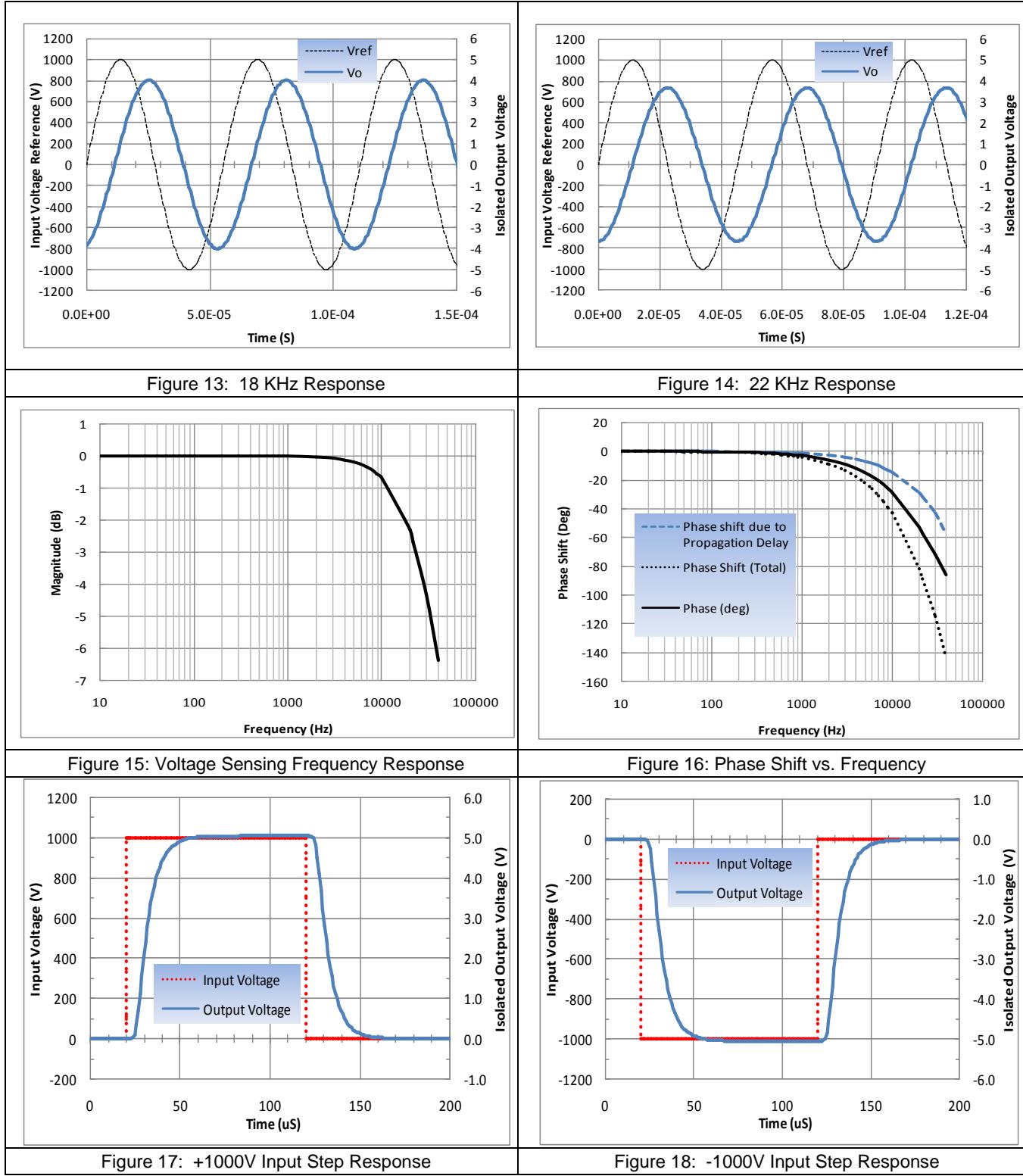
### PERFORMANCE CHARACTERISTICS (-Continue)

At  $T_A = +25^\circ\text{C}$ ,  $V_{cc} = +12\text{V}$ ,  $V_{ee} = -12\text{V}$ , and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.



### PERFORMANCE CHARACTERISTICS (Continue)

At  $T_A = +25^\circ\text{C}$ ,  $V_{cc} = +12\text{V}$ ,  $V_{ee} = -12\text{V}$ , and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.



### PERFORMANCE CHARACTERISTICS (Continue)

At  $T_A = +25^\circ\text{C}$ ,  $V_{cc} = +12\text{V}$ ,  $V_{ee} = -12\text{V}$ , and  $R_L = 10\text{k}\Omega$ , unless otherwise noted.

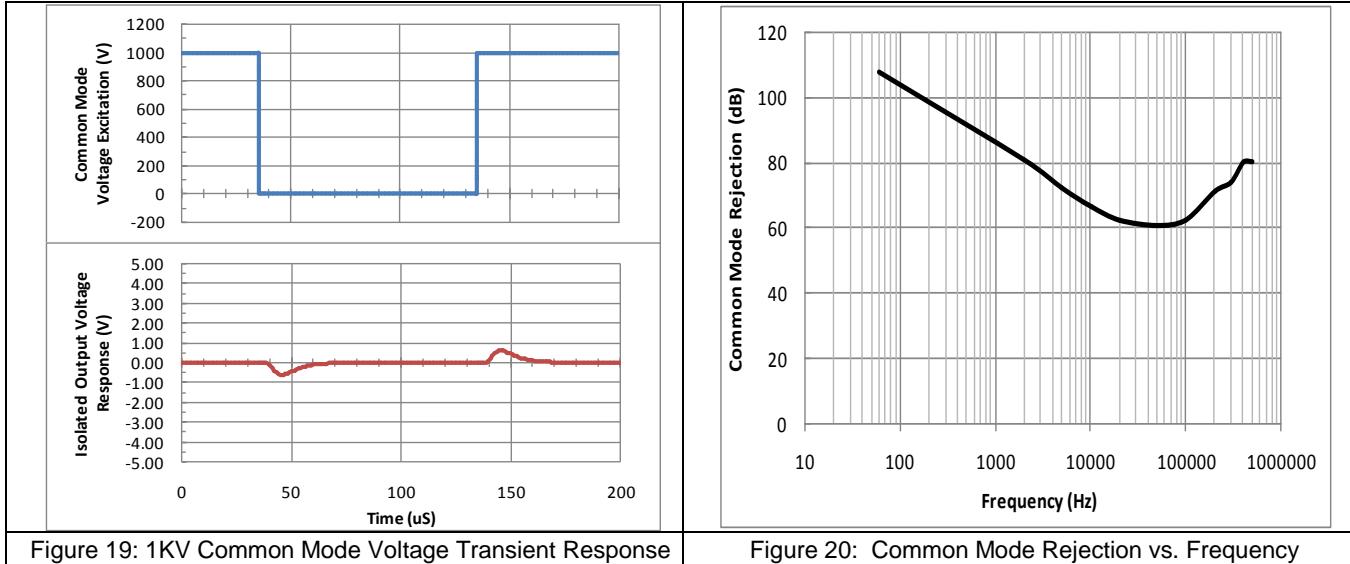


Figure 19: 1KV Common Mode Voltage Transient Response

Figure 20: Common Mode Rejection vs. Frequency

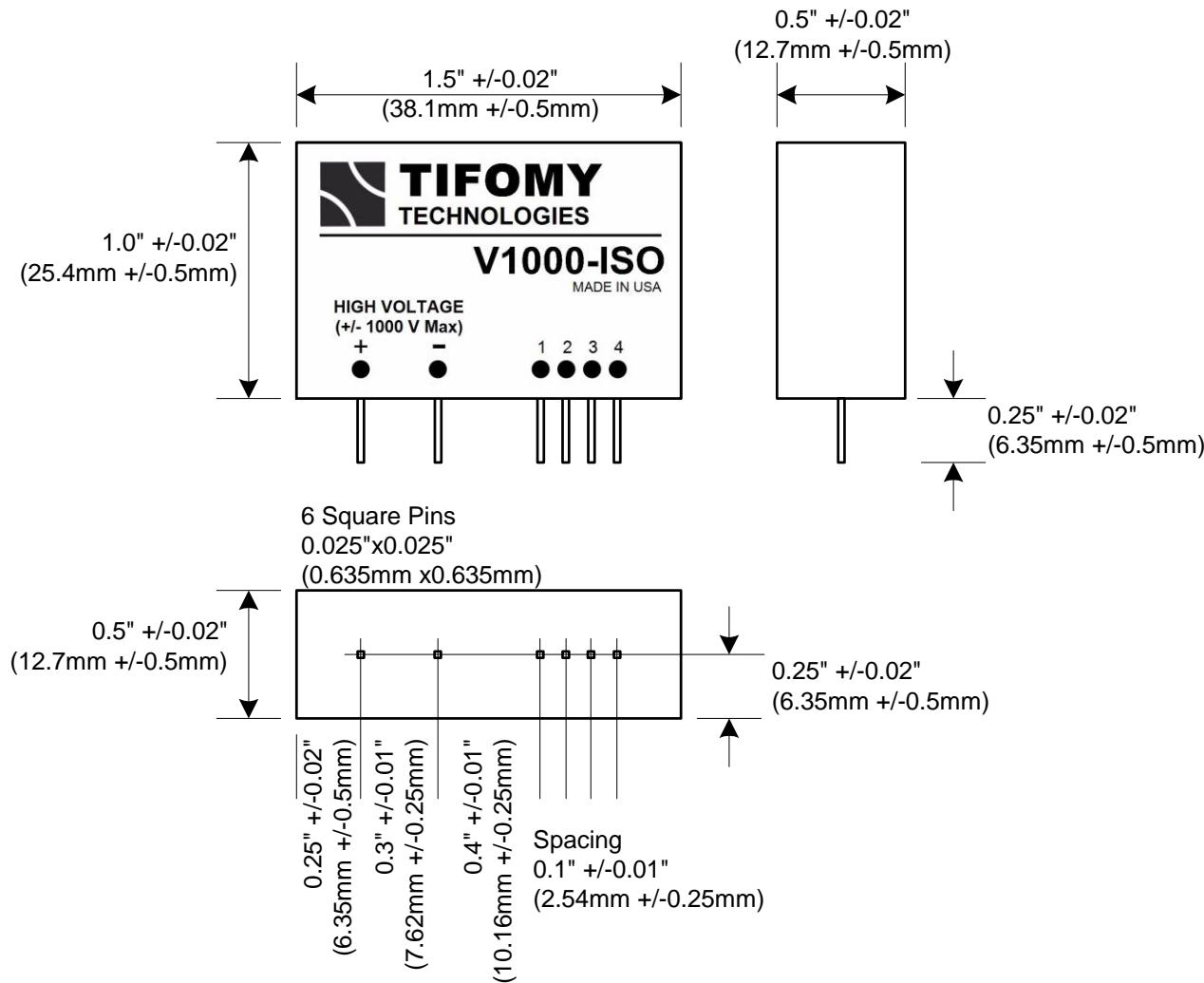
### NOTES:

1. The 3000Vrms 60Hz is applied between shorted high voltage pins ("+" and "-") and shorted low voltage pins (1, 2, 3, and 4) for a duration of 60 seconds at room temperature. Passing criteria is less than 70  $\mu\text{A}$ . Each device is 100% tested by this test.
2. Isolated output voltage (pin 4 - pin 3) is plotted as a function of high voltage input (pin "+" - pin "-"). Gain is defined as the ratio of output voltage (pin 4 – pin 3) and input voltage (pin "+" - pin "-").
3. Overall accuracy is defined as voltage error between measured output voltage and actual input voltage divided by 200, expressed as a percentage of the full-scale differential output voltage.
4. Gain vs. temperature is defined as gain deviation from the gain at  $25^\circ\text{C}$ , expressed as a percentage per degree C over the operating temperature range of  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .
5. Nonlinearity is defined as gain deviation from the best-fit gain line, expressed as a percentage of the full-scale differential output voltage.
6. See figure 23 for common mode rejection frequency response test setup.
7. See figure 24 for common mode rejection transient immunity test setup.
8. This is continuous voltage operation range. Maximum DC voltage operation is  $\pm 1000\text{V}$ . Maximum AC voltage operation is 707 Vrms. The amplitude of the AC voltage is  $1.414 \times 707 = 1000\text{V}$  for 707 Vrms.
9. The output voltage offset drift is defined as voltage deviation from the offset measured at  $25^\circ\text{C}$  with zero input voltage, expressed as per degree C over the operating temperature range of  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .
10. This is the output voltage response for a sinusoidal input voltage with fixed amplitude of 1000V and frequency from 60Hz to 22 KHz.
11. The propagation delay in terms of phase shift for sinusoidal voltage response is plotted in figure 16. The delay adds additional phase shift to the bandwidth of filtering network.
12. Calculation of MTBF (Mean Time Between Failure) is based on Mil-HDBK-217F Notice 2.

**TEST SETUP:**

<p>Leakage Current (<math>I_{LKG}</math>)</p> <p>3 KV rms 60 Hz, 60 seconds</p>	<p>Input Voltage or <math>V_{ref}</math></p> <p>+12V</p> <p>-12V</p>
<p>Common Mode Voltage Excitation Frequency: 60Hz - 500 KHz</p>	<p>Common Mode Voltage Excitation 1000V</p> <p>+12V</p> <p>-12V</p> <p>Output Response</p>
<p>Fig 21 Isolation (Hi-pot) Test Setup</p>	<p>Fig 22 Input Output Voltage Test Setup</p>
<p>Fig 23 Common Mode Rejection Frequency Response Test Setup</p>	<p>Fig 24 Common Mode Rejection Transient Immunity Test Setup</p>

#### PACKAGE OUTLINE:



#### PACKAGE WEIGHT:

0.741 oz (21 g)

#### WARNING!

 Danger! Electrical Shock Risk	<p>The exposed pins of the voltage transducer can carry hazardous voltage. The device must be used in a protective housing and the conducting parts must be inaccessible after installation. Ignoring this warning can lead to injury and/or serious damage.</p>
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